



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT(S): Etsuo Morita  
SERIAL NO. 09/726,860  
FILING DATE: November 30, 2000

ATTY. DOCKET NO. 09792909-4715  
GROUP ART UNIT: 1722  
EXAMINER: HITESHAW, Felisa

INVENTION: **"METHOD OF MANUFACTURING CRYSTAL OF III-V COMPOUND OF THE NITRIDE SYSTEM, CRYSTAL SUBSTRATE OF III-V COMPOUND OF THE NITRIDE SYSTEM, CRYSTAL FILM OF III-V COMPOUND OF THE NITRIDE SYSTEM, AND METHOD OF MANUFACTURING DEVICE"**

**RESPONSE TO OFFICE ACTION DATED JANUARY 31, 2006**

Mail Stop Amendment  
Commissioner of Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

S I R:

In response to the Office Action of January 31, 2006, please enter the attached Terminal Disclaimer. An extension of time and the appropriate fees are also included herewith.

In view of the foregoing, it is, submitted that the application is in condition for allowance.

Notice to that effect is respectfully requested.

Respectfully submitted,

Dated: July 31, 2006

By: R. Scott Kimsey  
R. Scott Kimsey  
Registration No. 50,195  
SONNENSCHN NATH & ROSENTHAL LLP  
P.O. Box 061080  
Wacker Drive Station, Sears Tower  
Chicago, Illinois 60606-1080  
(312) 876-8000